
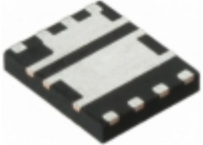
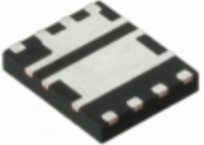
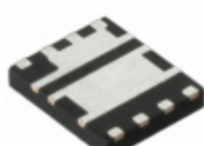
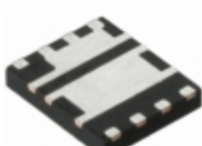




| | |
|---|---|
|  | <h2 style="color: red;">FDMS3600S</h2> |
| | <p>Hersteller-Teilenummer: FDMS3600S</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET 2N-CH 25V 15A/30A 8-PQFN</p> <p>Datenblätter:  FDMS3600S.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5302 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Artikelnummer | FDMS3600S |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET 2N-CH 25V 15A/30A 8-PQFN |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 5302 pcs Stock |
| VGS (th) (Max) @ Id | 2.7V @ 250µA |
| Supplier Device-Gehäuse | Power56 |
| Serie | PowerTrench® |
| Rds On (Max) @ Id, Vgs | 5.6 mOhm @ 15A, 10V |
| Leistung - max | 1W |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 8-PowerTDFN |
| Andere Namen | FDMS3600S-ND |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Hersteller Standard Vorlaufzeit | 39 Weeks |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Eingabekapazität (Ciss) (Max) @ Vds | 1680pF @ 13V |
| Gate Charge (Qg) (Max) @ Vgs | 27nC @ 10V |
| Typ FET | 2 N-Channel (Dual) Asymmetrical |
| FET-Merkmal | Logic Level Gate |
| Drain-Source-Spannung (Vdss) | 25V |
| detaillierte Beschreibung | Mosfet Array 2 N-Channel (Dual) Asymmetrical 25V 15A, |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 15A, 30A |
| Basisteilenummer | FDMS3600S |

Sie können auch interessiert

| | | | |
|---|---|--|--|
| <p>sein:</p>  <p>FDMS3600AS MOS FAIRCHILD FAIRCHILD QFN</p> |  <p>FDMS3572 MOS FAIRCHILD FAIRCHILD QFN</p> |  <p>FDMS3602S Fairchild/ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p> |  <p>FDMS3600AS Fairchild/ON Semiconductor MOSFET 2N-CH 25V 15A/30A 8-PQFN</p> |
|  <p>FDMS3600AS AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/30A 8-PQFN</p> |  <p>FDMS3602S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p> |  <p>FDMS3602S MOS FAIRCHILD FAIRCHILD SON8</p> |  <p>FDMS3602AS AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p> |

FDMS3600S Zugehöriges

Mehr

Schlüsselwort

| | | | | |
|--|-----------------------|------------------------|-----------------|--|
| FDMS3600S AMI Semiconductor / ON Semiconductor | FDMS3600S Datenblatt | FDMS3600S-Datenblätter | FDMS3600S PDF | AMI Semiconductor / ON Semiconductor FDMS3600S |
| FDMS3600S Electronic | FDMS3600S-Komponenten | FDMS3600S-Verteiler | FDMS3600S-Bild | FDMS3600S-Teil |
| FDMS3600S Preis | FDMS3600S Hersteller | FDMS3600S Bild | FDMS3600S Aktie | FDMS3600S Inventar |
| FDMS3600S Neu | FDMS3600S Original | FDMS3600S garantiert | FDMS3600S RFQ | FDMS3600S Online bestellen |

Contact us: Info@YIC-Electronics.com

HINZUFÜGEN: Einheit A5-B5 Nr. 509, 5 / F Sing Win-Fabrikgebäude, 15-17 Shing Yip Street, Kwun Tong, Kowloon, Hongkong.

Copyright © 2023 YIC-Electronics.com - YIC International Co., Limited